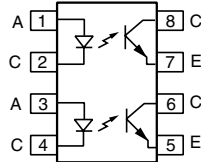
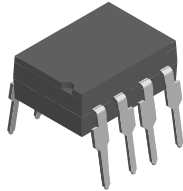
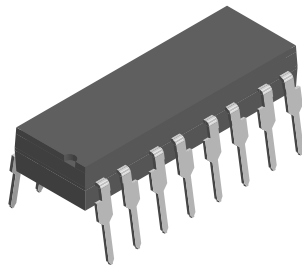
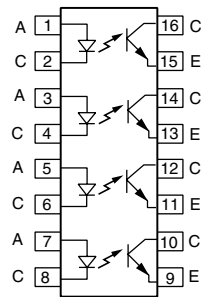


Optocoupler, Phototransistor Output, (Dual, Quad Channel), 110 °C Rated

Dual Channel

Quad Channel


1179052



FEATURES

- Operating temperature from - 55 °C to + 110 °C
- Identical channel to channel footprint
- Dual and quad packages feature:
 - Reduced board space
 - Lower pin and parts count
 - Better channel to channel CTR match
 - Improved common mode rejection
- Isolation test voltage, 5300 V_{RMS}
- Lead (Pb)-free component
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC


RoHS
COMPLIANT

AGENCY APPROVALS

- UL1577, file no. E52744 system code H or J, double protection
- CSA 93751
- BSI IEC 60950; IEC 60065
- DIN EN 60747-5-2 (VDE 0884)/DIN EN 60747-5-5 pending available with option 1

DESCRIPTION

The ILD/Q1615 are multi-channel 110 °C rated phototransistor optocouplers that use GaAs IRLED emitters and high gain NPN phototransistors. These devices are constructed using over/under leadframe optical coupling and double molded insulation technology resulting a withstand test voltage of 7500 V_{ACPEAK} and a working voltage of 1700 V_{RMS}.

The binned min./max. and linear CTR characteristics make these devices well suited for DC or AC voltage detection. Eliminating the phototransistor base connection provides added electrical noise immunity from the transients found in many industrial control environments.

Because of guaranteed maximum non-saturated and saturated switching characteristics, the ILD/Q1615 can be used in medium speed data I/O and control systems. The binned min./max. CTR specification allow easy worst case interface calculations for both level detection and switching applications. Interfacing with a CMOS logic is enhanced by the guaranteed CTR at I_F = 1.0 mA.

ILD1615/ILQ1615



Vishay Semiconductors Optocoupler, Phototransistor Output,
(Dual, Quad Channel), 110 °C Rated

ORDER INFORMATION	
PART	REMARKS
ILD1615-1	CTR 40 to 80 %, DIP-8
ILQ1615-1	CTR 40 to 80 %, DIP-16
ILD1615-2	CTR 63 to 125 %, DIP-8
ILQ1615-2	CTR 63 to 125 %, DIP-16
ILD1615-3	CTR 100 to 200 %, DIP-8
ILQ1615-3	CTR 100 to 200 %, DIP-16
ILD1615-4	CTR 160 to 320 %, DIP-8
ILQ1615-4	CTR 160 to 320 %, DIP-16

Note

For additional information on the available options refer to option information.

ABSOLUTE MAXIMUM RATINGS (1)				
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
INPUT				
Peak reverse voltage		V_R	6.0	V
Forward current		I_F	60	mA
Surge current		I_{FSM}	1.5	A
Power dissipation		P_{diss}	100	mW
Derate linearly from 25 °C			1.0	mW/°C
OUTPUT				
Collector emitter breakdown voltage		BV_{CEO}	70	V
Emitter collector breakdown voltage		BV_{ECO}	7.0	V
Collector current		I_C	50	mA
	$t < 1.0$ ms	I_C	100	mA
Power dissipation		P_{diss}	150	mW
Derate linearly from 25 °C			1.5	mW/°C
COUPLER				
Storage temperature		T_{stg}	- 55 to + 150	°C
Operating temperature		T_{amb}	- 55 to + 110	°C
Soldering temperature (2)	2.0 mm distance from case bottom	T_{sld}	260	°C
Package power dissipation ILD1615			400	mW
Derate linearly from 25 °C			5.33	mW/°C
Package power dissipation ILQ1615			500	mW
Derate linearly from 25 °C			6.67	mW/°C
Isolation test voltage	$t = 1.0$ s	V_{ISO}	5300	V_{RMS}
Creepage distance			≥ 7.0	mm
Clearance distance			≥ 7.0	mm
Isolation resistance	$V_{IO} = 500$ V, $T_{amb} = 25$ °C	R_{IO}	$\geq 10^{12}$	Ω
	$V_{IO} = 500$ V, $T_{amb} = 100$ °C	R_{IO}	$\geq 10^{11}$	Ω

Note

(1) $T_{amb} = 25$ °C, unless otherwise specified.

Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute maximum ratings for extended periods of the time can adversely affect reliability.

(2) Refer to wave profile for soldering conditions for through hole devices.



ELECTRICAL CHARACTERISTICS						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
INPUT						
Forward voltage	$I_F = 1.0 \text{ mA}$	V_F	1.0	1.15	1.3	V
Breakdown voltage	$I_R = 10 \text{ }\mu\text{A}$	V_{BR}	6.0	30		V
Reverse current	$V_R = 6.0 \text{ V}$	I_R		0.01	10	μA
Capacitance	$V_R = 0 \text{ V}, f = 1.0 \text{ MHz}$	C_O		25		pF
OUTPUT						
Collector emitter capacitance	$V_{CE} = 5.0 \text{ V}, f = 1.0 \text{ MHz}$	C_{CE}		6.8		pF
Collector emitter leakage current, -1, -2	$V_{CE} = 10 \text{ V}$	I_{CEO}		2.0	50	nA
Collector emitter leakage current, -3, -4	$V_{CE} = 10 \text{ V}$	I_{CEO}		5.0	100	nA
Collector emitter breakdown voltage	$I_{CE} = 0.5 \text{ mA}$	BV_{CEO}	70			V
Emitter collector breakdown voltage	$I_E = 0.1 \text{ mA}$	BV_{ECO}	7.0			V
PACKAGE TRANSFER CHARACTERISTICS						
Channel/channel CTR match	$I_F = 10 \text{ mA}, V_{CE} = 5.0 \text{ V}$	CTR _X /CTR _Y	1 to 1		2 to 1	
COUPLER						
Capacitance (input to output)	$V_{IO} = 0 \text{ V}, f = 1.0 \text{ MHz}$	C_{IO}		0.8		pF
Insulation resistance	$V_{IO} = 500 \text{ V}, T_A = 25 \text{ }^\circ\text{C}$	R_S	10^{12}	10^{14}		Ω
Channel to channel isolation			500			VAC

Note

$T_{amb} = 25 \text{ }^\circ\text{C}$, unless otherwise specified.

Minimum and maximum values are tested requirements. Typical values are characteristics of the device and are the result of engineering evaluations. Typical values are for information only and are not part of the testing requirements.

CURRENT TRANSFER RATIO																															
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT																								
Current transfer ratio (collector emitter saturated)	$I_F = 1.0 \text{ mA}, V_{CE} = 0.4 \text{ V}$	ILD1615-1	CTR _{CEsat}		25		%																								
		ILQ1615-1																													
		ILD1615-2	CTR _{CEsat}						40		%																				
		ILQ1615-2																													
		ILD1615-3	CTR _{CEsat}										60		%																
		ILQ1615-3																													
ILD1615-4	CTR _{CEsat}		100		%																										
ILQ1615-4																															
Current transfer ratio (collector emitter)	$I_F = 10 \text{ mA}, V_{CE} = 5.0 \text{ V}$					ILD1615-1	CTR _{CE}	40	60	80	%																				
						ILQ1615-1																									
	$I_F = 1.0 \text{ mA}, V_{CE} = 5.0 \text{ V}$					ILD1615-1	CTR _{CE}					13	30		%																
						ILQ1615-1																									
	$I_F = 10 \text{ mA}, V_{CE} = 5.0 \text{ V}$	ILD1615-2	CTR _{CE}	63	80	125	%																								
		ILQ1615-2																													
	$I_F = 1.0 \text{ mA}, V_{CE} = 5.0 \text{ V}$	ILD1615-2	CTR _{CE}													22	45		%												
		ILQ1615-2																													
	$I_F = 10 \text{ mA}, V_{CE} = 5.0 \text{ V}$	ILD1615-3	CTR _{CE}																	100	150	200	%								
		ILQ1615-3																													
	$I_F = 1.0 \text{ mA}, V_{CE} = 5.0 \text{ V}$	ILD1615-3	CTR _{CE}																					34	70		%				
		ILQ1615-3																													
	$I_F = 10 \text{ mA}, V_{CE} = 5.0 \text{ V}$	ILD1615-4	CTR _{CE}																									160	200	320	%
		ILQ1615-4																													
$I_F = 1.0 \text{ mA}, V_{CE} = 5.0 \text{ V}$	ILD1615-4	CTR _{CE}	56					90		%																					
	ILQ1615-4																														



SWITCHING CHARACTERISTICS							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
SATURATED							
Propagation H to L	$I_F = 5.0 \text{ mA}, V_{CC} = 5.0 \text{ V}, R_L = 1.0 \text{ k}\Omega, V_{HT} = 1.5 \text{ V}$	ILD1615-1	t_{PHL}		1.6		μs
		ILQ1615-1					
		ILD1615-2	t_{PHL}		2.6		μs
		ILQ1615-2					
		ILD1615-3	t_{PHL}		2.6		μs
		ILQ1615-3					
ILD1615-4	t_{PHL}		5.4		μs		
ILQ1615-4							
Propagation L to H	$I_F = 5.0 \text{ mA}, V_{CC} = 5.0 \text{ V}, R_L = 1.0 \text{ k}\Omega, V_{HT} = 1.5 \text{ V}$	ILD1615-1	t_{PLH}		8.6		μs
		ILQ1615-1					
		ILD1615-2	t_{PLH}		7.2		μs
		ILQ1615-2					
		ILD1615-3	t_{PLH}		7.2		μs
		ILQ1615-3					
ILD1615-4	t_{PLH}		7.4		μs		
ILQ1615-4							

COMMON MODE TRANSIENT IMMUNITY							
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT	
Common mode rejection output high	$V_{CM} = 50 \text{ V}_{P-P}, R_L = 1.0 \text{ k}\Omega, I_F = 0 \text{ mA}$	CM_H		5000		$\text{V}/\mu\text{s}$	
Common mode rejection output low	$V_{CM} = 50 \text{ V}_{P-P}, R_L = 1.0 \text{ k}\Omega, I_F = 0 \text{ mA}$	CM_L		5000		$\text{V}/\mu\text{s}$	
Common mode coupling capacitance		C_{CM}		0.01		pF	

TYPICAL CHARACTERISTICS

$T_{amb} = 25 \text{ }^\circ\text{C}$, unless otherwise specified

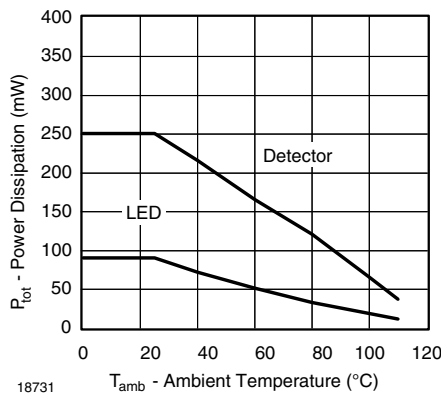


Fig. 1 - Permissible Power Dissipation vs. Temperature Non-Saturation Operation

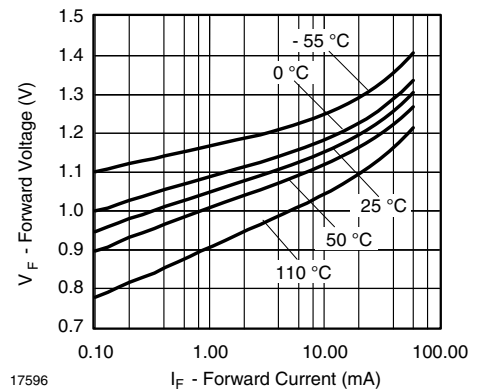


Fig. 2 - Forward Voltage vs. Forward Current

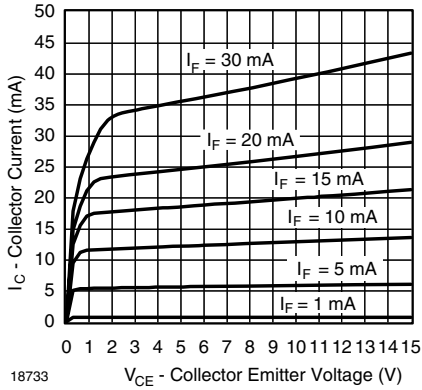


Fig. 3 - Collector Current vs. Collector Emitter Voltage

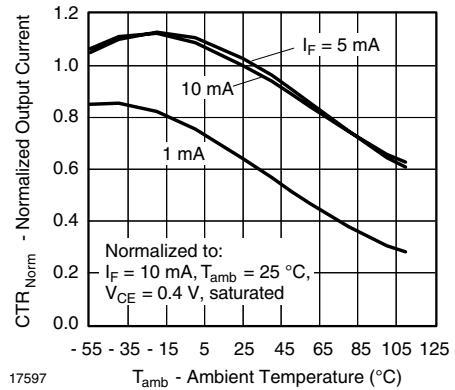


Fig. 6 - Normalized Current Transfer Ratio vs. Ambient Temperature

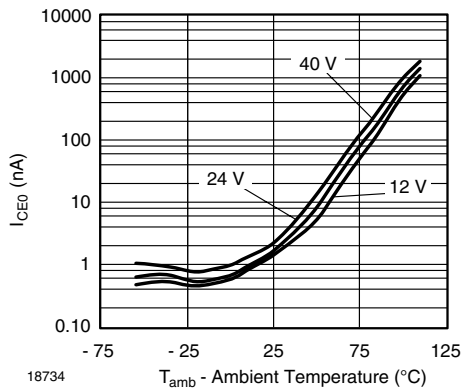


Fig. 4 - Collector to Emitter Dark Current vs. Ambient Temperature

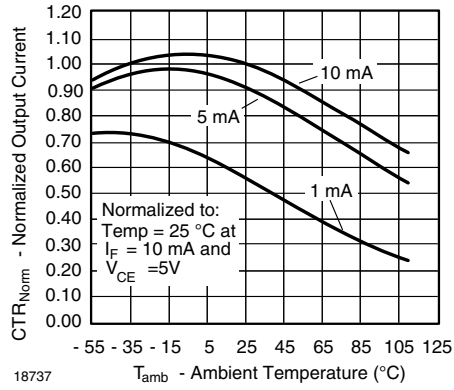


Fig. 7 - Normalized CTR vs. Temperature

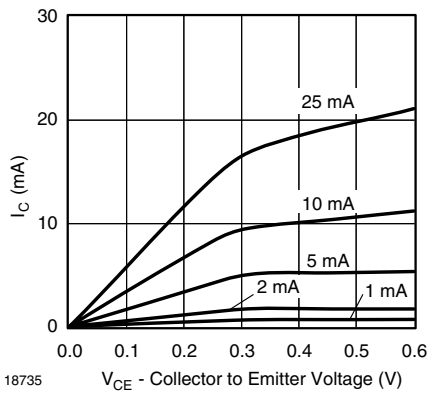


Fig. 5 - Normalized Current vs. Collector Emitter Saturation Voltage

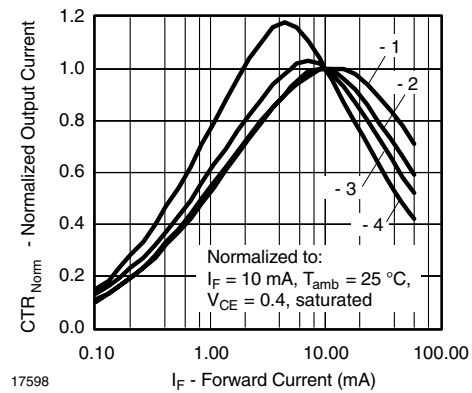


Fig. 8 - Normalized CTR vs. Forward Current

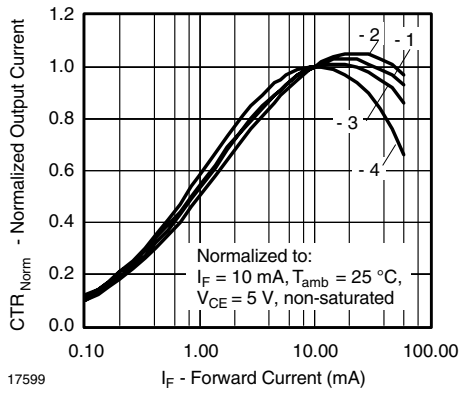


Fig. 9 - Normalized CTR vs. Forward Current

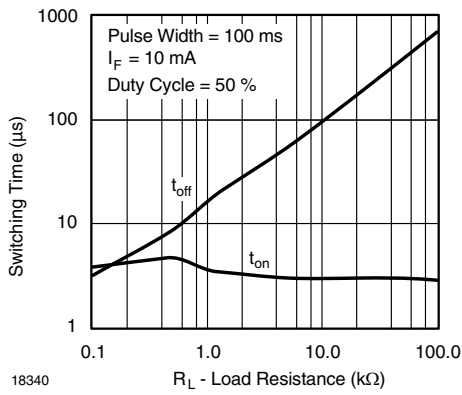


Fig. 10 - Forward Resistance vs. Forward Current

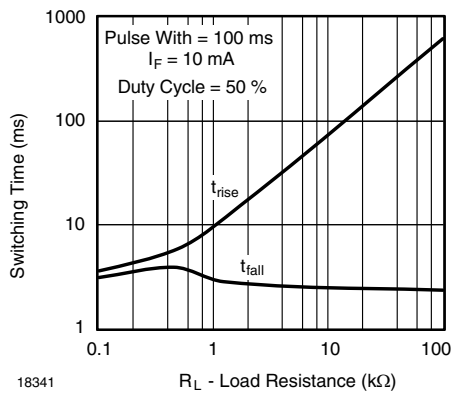


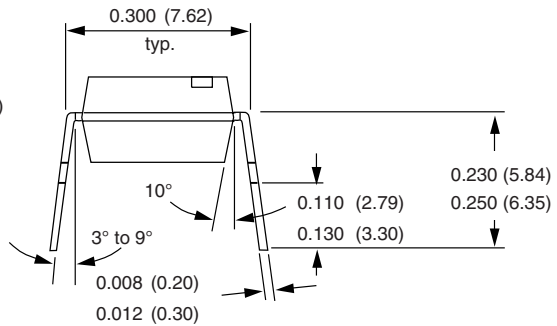
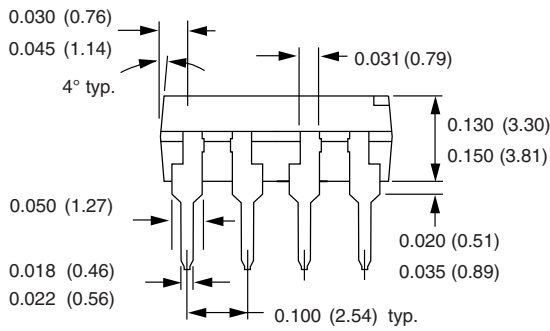
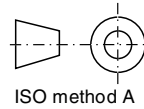
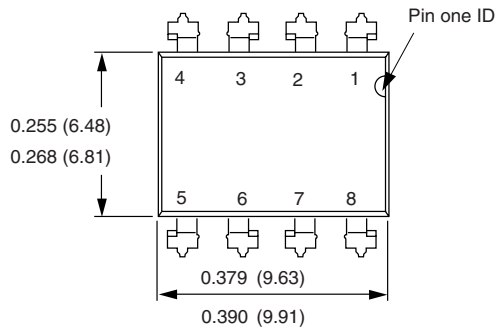
Fig. 11 - Forward Resistance vs. Forward Current

ILD1615/ILQ1615

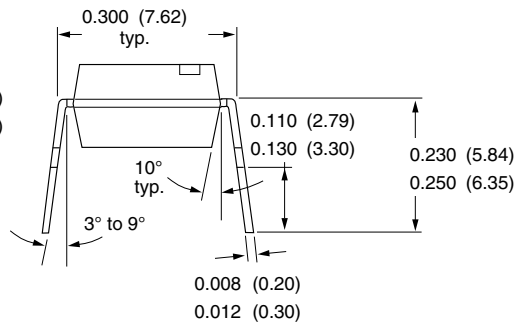
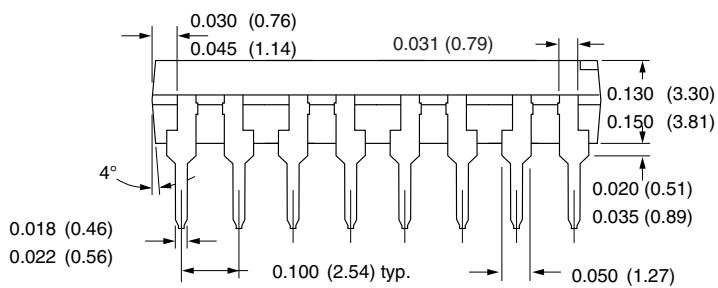
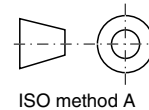
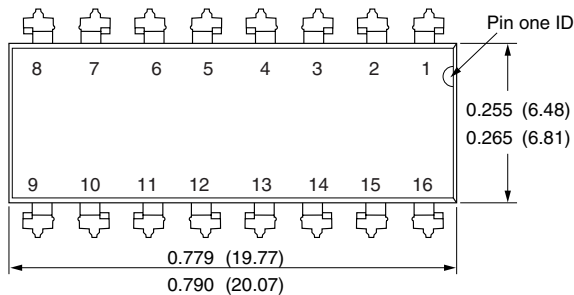


Vishay Semiconductors Optocoupler, Phototransistor Output,
(Dual, Quad Channel), 110 °C Rated

PACKAGE DIMENSIONS in inches (millimeters)



i178006



i178007

**OZONE DEPLETING SUBSTANCES POLICY STATEMENT**

It is the policy of Vishay Semiconductor GmbH to

1. Meet all present and future national and international statutory requirements.
2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively.
2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA.
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design
and may do so without further notice.

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay Semiconductors products for any unintended or unauthorized application, the buyer shall indemnify Vishay Semiconductors against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

Vishay Semiconductor GmbH, P.O.B. 3535, D-74025 Heilbronn, Germany



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